

# NX3DV42

## Dual high-speed USB 2.0 double-pole double-throw analog switch

Rev. 1 — 3 January 2012

Product data sheet

### 1. General description

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The NX3DV42 is a double-pole double-throw analog switch suitable for use as an analog or digital multiplexer/demultiplexer. Its wide bandwidth and low bit-to-bit skew allows the NX3DV42 to pass high-speed differential signals with good signal integrity. Its high channel to channel crosstalk rejection results in minimal noise interference. The bandwidth is wide enough to pass high-speed USB 2.0 differential signals (480 Mb/s). It consist of two switches, each with two independent input/outputs (HSDn+ and HSDn-) and a common input/output (D+ or D-). One digital inputs (S) is used to select the switch position. When pin OE is HIGH, the switches are turned off. Schmitt trigger action at the select input (S) and enable input ( $\overline{OE}$ ) makes the circuit tolerant to slower input rise and fall times across the entire  $V_{CC}$  range from 3.0 V to 4.3 V.

### 2. Features and benefits

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- Supply voltage range from 3.0 V to 4.3 V
- 4  $\Omega$  typical ON resistance
- 7.3 pF typical ON capacitance
- 950 MHz typical bandwidth or data frequency
- Low crosstalk of -30 dB at 240 MHz
- Break-before-make switching
- ESD protection:
  - ◆ HBM JESD22-A114F Class 3A exceeds 4000 V
  - ◆ CDM AEC-Q100-011 revision B exceeds 1000 V
  - ◆ HBM exceeds 12000 V for power to GND protection
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level A
- Specified from -40 °C to +85 °C

### 3. Applications

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- Cell phone, PDA, Digital camera and notebook
- LCD monitor, TV and set-top box



## 4. Ordering information

Table 1. Ordering information

Type number	Package			Version
	Temperature range	Name	Description	
NX3DV42GM	-40 °C to +85 °C	XQFN10U	plastic extremely thin quad flat package; no leads; 10 terminals; UTLP based; body 2 × 1.55 × 0.5 mm	SOT1049-2
NX3DV42GU	-40 °C to +85 °C	XQFN10	plastic, extremely thin quad flat package; no leads; 10 terminals; body 1.40 x 1.80 x 0.50 mm	SOT1160-1

## 5. Marking

Table 2. Marking

Type number	Marking code
NX3DV42GM	x4
NX3DV42GU	x4

## 6. Functional diagram

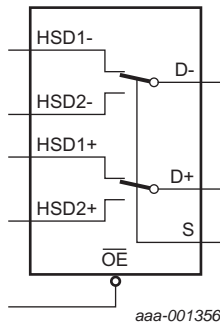
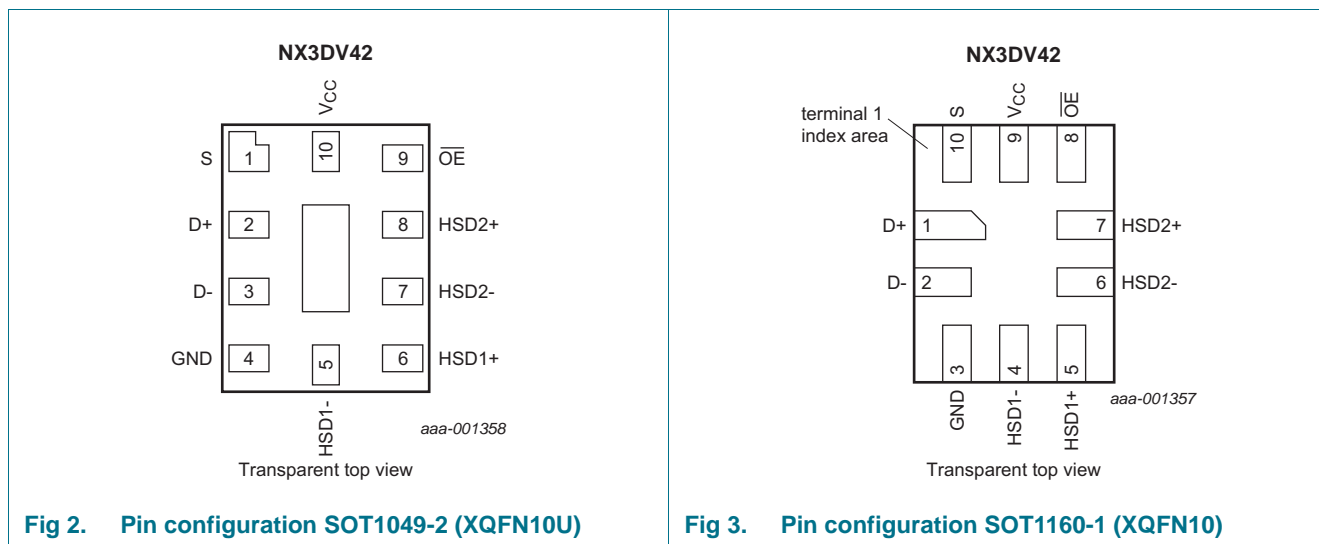


Fig 1. Logic symbol

## 7. Pinning information

### 7.1 Pinning



### 7.2 Pin description

Table 3. Pin description

Symbol	Pin		Description
	SOT1049-2	SOT1160-1	
HSD1-, HSD2-	5, 7	4, 6	independent input or output
HSD1+, HSD2+	6, 8	5, 7	independent input or output
D+, D-	2, 3	1, 2	common output or input
GND	4	3	ground (0 V)
OE	9	8	output enable input (active-LOW)
S	1	10	select input
V <sub>CC</sub>	10	9	supply voltage

## 8. Functional description

Table 4. Function table<sup>[1]</sup>

Input	Channel on	
S	OE	
L	L	HSD1+ and HSD1-
H	L	HSD2+ and HSD2-
X	H	switch off

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care.

## 9. Limiting values

**Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		-0.5	+5.5	V
$V_I$	input voltage	pins S and $\overline{OE}$	[1] -0.5	$V_{CC}$	V
$V_{SW}$	switch voltage		-0.5	+5.5	V
$I_{IK}$	input clamping current	$V_I < -0.5$ V	-50	-	mA
$I_{SK}$	switch clamping current	$V_I < -0.5$ V	-	$\pm 50$	mA
$I_{SW}$	switch current		-	$\pm 100$	mA
$I_{CC}$	supply current		-	+50	mA
$T_{stg}$	storage temperature		-65	+150	°C
$P_{tot}$	total power dissipation	$T_{amb} = -40$ °C to +85 °C	-	250	mW

[1] The minimum input voltage rating may be exceeded if the input current rating is observed.

## 10. Recommended operating conditions

**Table 6. Recommended operating conditions**

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		3.0	4.3	V
$V_I$	input voltage	pins S and $\overline{OE}$	0	$V_{CC}$	V
$V_{SW}$	switch voltage		[1] 0	4.5	V
$T_{amb}$	ambient temperature		-40	+85	°C

[1] To avoid sinking GND current from terminals D+ and D- when switch current flows in terminals HSDn+ and HSDn-, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminals D+ and D-, no GND current will flow from terminals HSDn+ and HSDn-. In this case, there is no limit for the voltage drop across the switch.

## 11. Static characteristics

**Table 7. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground 0 V).

Symbol	Parameter	Conditions	$T_{amb} = -40$ °C to +85 °C			Unit
			Min	Typ [1]	Max	
$V_{IH}$	HIGH-level input voltage	$V_{CC} = 3.0$ V to 3.6 V	1.3	-	-	V
		$V_{CC} = 4.3$ V	1.7	-	-	V
$V_{IL}$	LOW-level input voltage	$V_{CC} = 3.0$ V to 3.6 V	-	-	0.5	V
		$V_{CC} = 4.3$ V	-	-	0.7	V
$V_{IK}$	input clamping voltage	$V_{CC} = 3.0$ V; $I_I = -18$ mA	-	-	-1.2	V
$I_I$	input leakage current	pins S and $\overline{OE}$ ; $V_I =$ GND to 4.3 V; $V_{CC} = 4.3$ V	-	-	$\pm 1$	$\mu$ A
$I_{S(OFF)}$	OFF-state leakage current	$V_{CC} = 4.3$ V; see <a href="#">Figure 4</a>	-	-	$\pm 2$	$\mu$ A

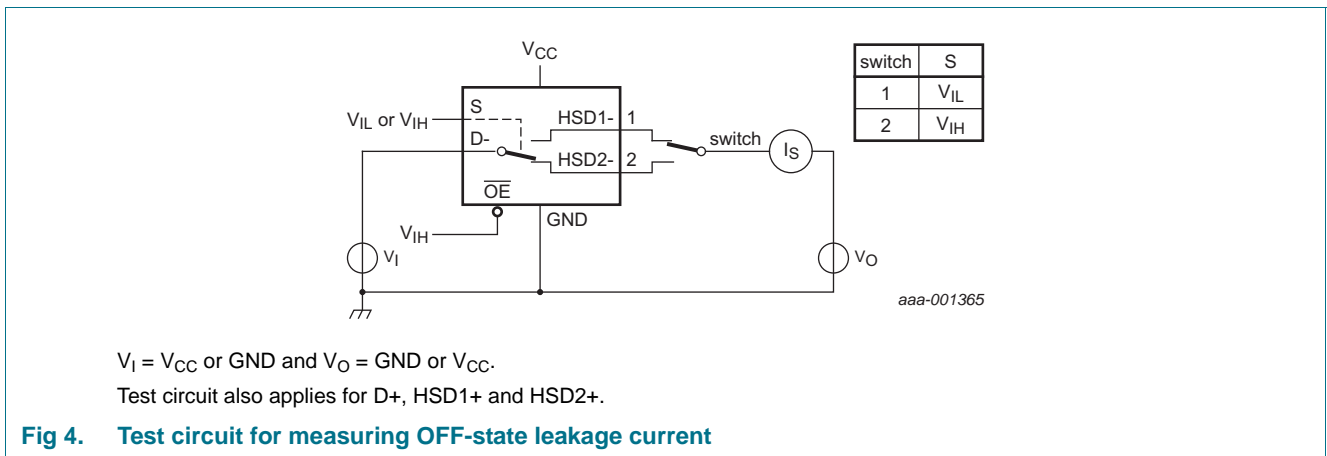
**Table 7. Static characteristics ...continued**

At recommended operating conditions; voltages are referenced to GND (ground 0 V).

Symbol	Parameter	Conditions	T <sub>amb</sub> = -40 °C to +85 °C			Unit
			Min	Typ <sup>[1]</sup>	Max	
I <sub>OFF</sub>	power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 4.3 V; V <sub>CC</sub> = 0 V	-	-	±2	μA
I <sub>CC</sub>	supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>SW</sub> = GND or V <sub>CC</sub> ; V <sub>CC</sub> = 4.3 V	-	-	1	μA
ΔI <sub>CC</sub>	additional supply current	V <sub>I</sub> = 2.6 V; V <sub>SW</sub> = GND or V <sub>CC</sub> ; V <sub>CC</sub> = 4.3 V	-	-	10	μA
		V <sub>I</sub> = 1.8 V; V <sub>SW</sub> = GND or V <sub>CC</sub> ; V <sub>CC</sub> = 4.3 V	-	-	15	μA
C <sub>I</sub>	input capacitance	pins S and OE	-	1.0	-	pF
C <sub>S(OFF)</sub>	OFF-state capacitance	pins HSDn+ and HSDn-; V <sub>CC</sub> = 3.3 V; V <sub>I</sub> = 0 V to 3.3 V	-	2.8	-	pF
C <sub>S(ON)</sub>	ON-state capacitance	pins D+ and D-; V <sub>CC</sub> = 3.3 V; V <sub>I</sub> = 0 V to 3.3 V	-	7.3	-	pF

[1] Typical values are measured at T<sub>amb</sub> = 25 °C and V<sub>CC</sub> = 3.3 V.

11.1 Test circuits



11.2 ON resistance

**Table 8. ON resistance**

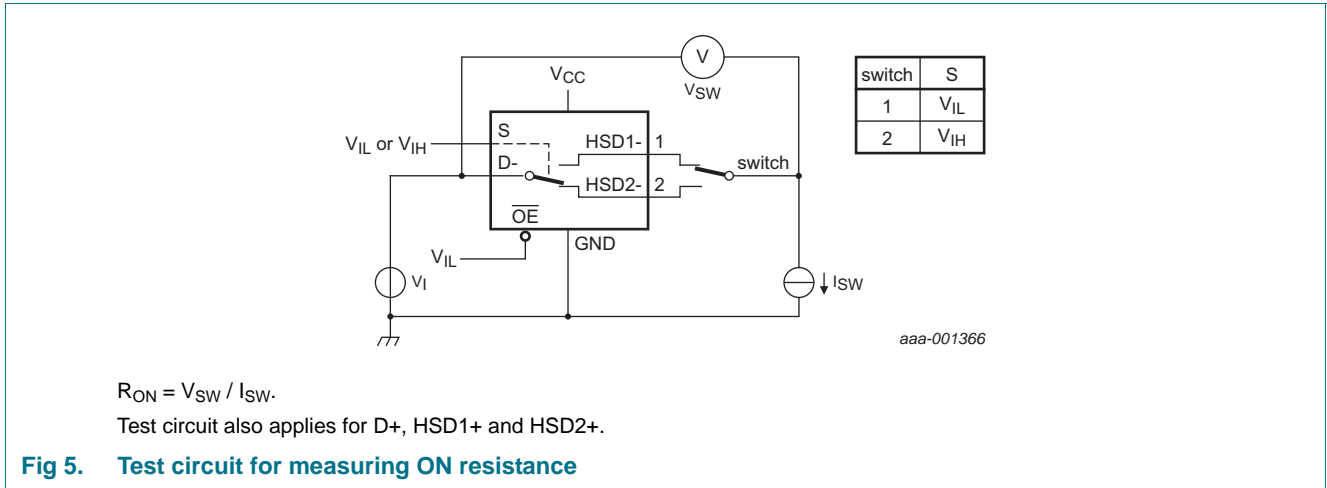
At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40 °C to +85 °C			Unit
			Min	Typ <sup>[1]</sup>	Max	
R <sub>ON</sub>	ON resistance	V <sub>I</sub> = 0.4 V; I <sub>SW</sub> = 8 mA; see <a href="#">Figure 5</a> V <sub>CC</sub> = 3.0 V	-	3.9	6.5	Ω
ΔR <sub>ON</sub>	ON resistance mismatch between channels	V <sub>I</sub> = 0.4 V; I <sub>SW</sub> = 8 mA V <sub>CC</sub> = 3.0 V	-	0.65	-	Ω

[1] Typical values are measured at T<sub>amb</sub> = 25 °C.

[2] Measured at identical V<sub>CC</sub>, temperature and input voltage.

11.3 ON resistance test circuit and graphs



12. Dynamic characteristics

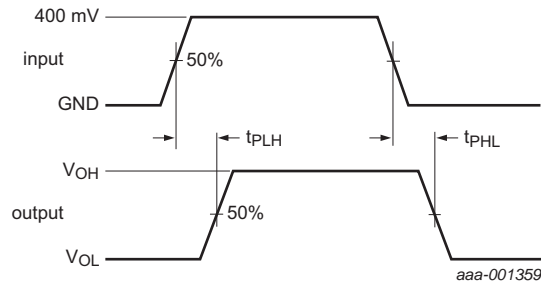
Table 9. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit see Figure 9.

Symbol	Parameter	Conditions	T <sub>amb</sub> = -40 °C to +85 °C			Unit
			Min	Typ <sup>[1]</sup>	Max	
t <sub>pd</sub>	propagation delay	HSDn+ to D+ or HSDn- to D- or D+ to HSDn+ or D- to HSDn-; see Figure 6 [2][3] V <sub>CC</sub> = 3.3 V	-	0.25	-	ns
t <sub>en</sub>	enable time	S or $\overline{OE}$ to D+ or D-; see Figure 7 [4] V <sub>CC</sub> = 3.0 V to 3.6 V	-	11.2	30	ns
t <sub>dis</sub>	disable time	S or $\overline{OE}$ to D+ or D-; see Figure 7 [5] V <sub>CC</sub> = 3.0 V to 3.6 V	-	3.9	25	ns
t <sub>b-m</sub>	break-before-make time	see Figure 8 [3] V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	5.9	-	ns
t <sub>sk(p)</sub>	pulse skew time	see Figure 6 [3] V <sub>CC</sub> = 3.0 V to 3.6 V	-	20	-	ps
t <sub>jit</sub>	jitter time	R <sub>L</sub> = 50 Ω; C <sub>L</sub> = 5 pF; t <sub>r</sub> , t <sub>f</sub> = 500 ps (10% to 90 %) at 480 Mbs (PRBS = 2 <sup>15</sup> - 1) [3]	-	200	-	ps

- [1] Typical values are measured at T<sub>amb</sub> = 25 °C, C<sub>L</sub> = 5 pF and V<sub>CC</sub> = 3.3 V.
- [2] t<sub>pd</sub> is the same as t<sub>PLH</sub> and t<sub>PHL</sub>.
- [3] Guaranteed by design.
- [4] t<sub>en</sub> is the same as t<sub>PZH</sub>
- [5] t<sub>dis</sub> is the same as t<sub>PHZ</sub>

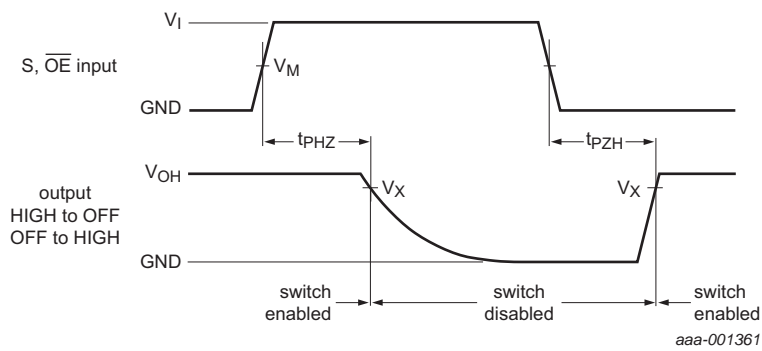
12.1 Waveform and test circuits



Logic levels:  $V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

$$t_{sk(p)} = |t_{PHL} - t_{PLH}|$$

Fig 6. The data input to output propagation delay times and pulse skew times



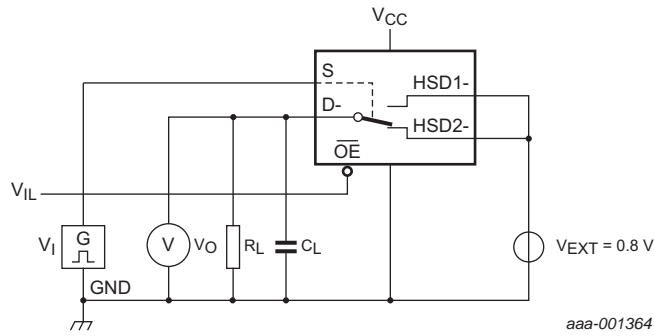
Measurement points are given in [Table 10](#).

Logic level:  $V_{OH}$  and  $V_{OL}$  are typical output voltage levels that occur with the output load.

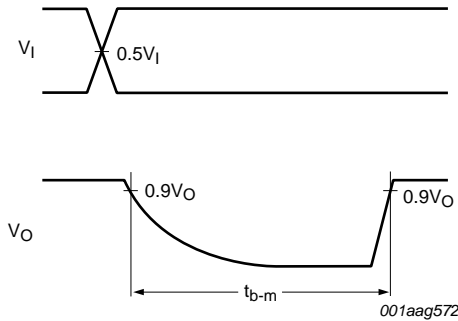
Fig 7. Enable and disable times

Table 10. Measurement points

Supply voltage	Input		Output
$V_{CC}$	$V_M$	$V_I$	$V_X$
3.0 V to 3.6 V	$0.5V_{CC}$	$V_{CC}$	$0.9V_{OH}$



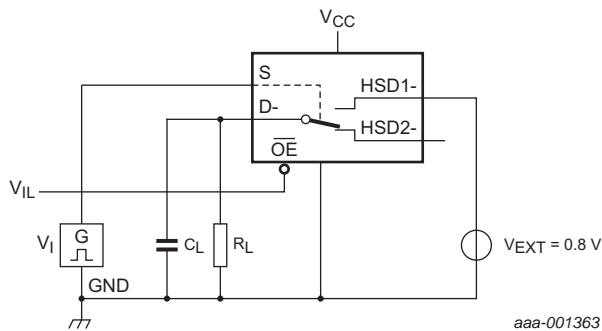
a. Test circuit.



b. Input and output measurement points

Test circuit also applies for D+, HSD1+ and HSD2+.

**Fig 8. Test circuit for measuring break-before-make timing**



Test circuit also applies for D+, HSD1+ and HSD2+.

Test data is given in [Table 11](#).

Definitions test circuit:

$R_T$  = Termination resistance (should be equal to output impedance  $Z_o$  of the pulse generator).

$R_L$  = Load resistance.

$C_L$  = Load capacitance including jig and probe capacitance.

$V_{EXT}$  = External voltage for measuring switching times.

$V_I$  may be connected to S or  $\overline{OE}$ .

**Fig 9. Test circuit for measuring switching times**



Table 11. Test data

Supply voltage	Input		Load	
$V_{CC}$	$V_I$	$t_r, t_f$	$C_L$	$R_L$
3.0 V to 3.6 V	$V_{CC}$	$\leq 2.5$ ns	5 pF	50 $\Omega$

12.2 Additional dynamic characteristics

Table 12. Additional dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V);  $V_I = GND$  or  $V_{CC}$  (unless otherwise specified);  $t_r = t_f \leq 2.5$  ns.

Symbol	Parameter	Conditions	$T_{amb} = 25$ °C			Unit
			Min	Typ <sup>[2]</sup>	Max	
$f_{(-3dB)}$	-3 dB frequency response	$R_L = 50 \Omega$ ; see <a href="#">Figure 10</a>				
		$C_L = 0$ pF; $V_{CC} = 3.0$ V to 3.6 V	-	950	-	MHz
		$C_L = 5$ pF; $V_{CC} = 3.0$ V to 3.6 V	-	450	-	MHz
$\alpha_{iso}$	isolation (OFF-state)	$f_i = 240$ MHz; $R_L = 50 \Omega$ ; see <a href="#">Figure 11</a> $V_{CC} = 3.0$ V to 3.6 V	-	-30	-	dB
Xtalk	crosstalk	between switches; $f_i = 240$ MHz; $R_L = 50 \Omega$ ; see <a href="#">Figure 12</a> $V_{CC} = 3.0$ V to 3.6 V	-	-30	-	dB

[1]  $f_i$  is biased at  $0.5V_{CC}$ .

[2] Typical values are measured at  $T_{amb} = 25$  °C and  $V_{CC} = 3.3$  V.

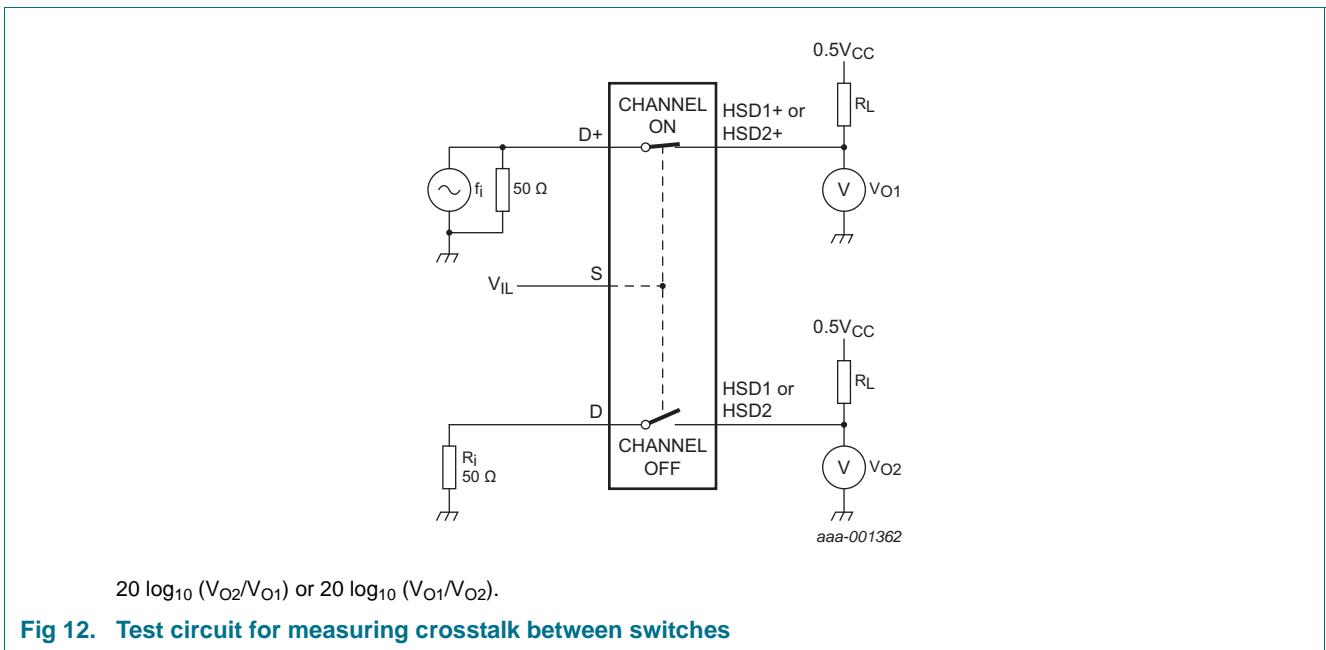
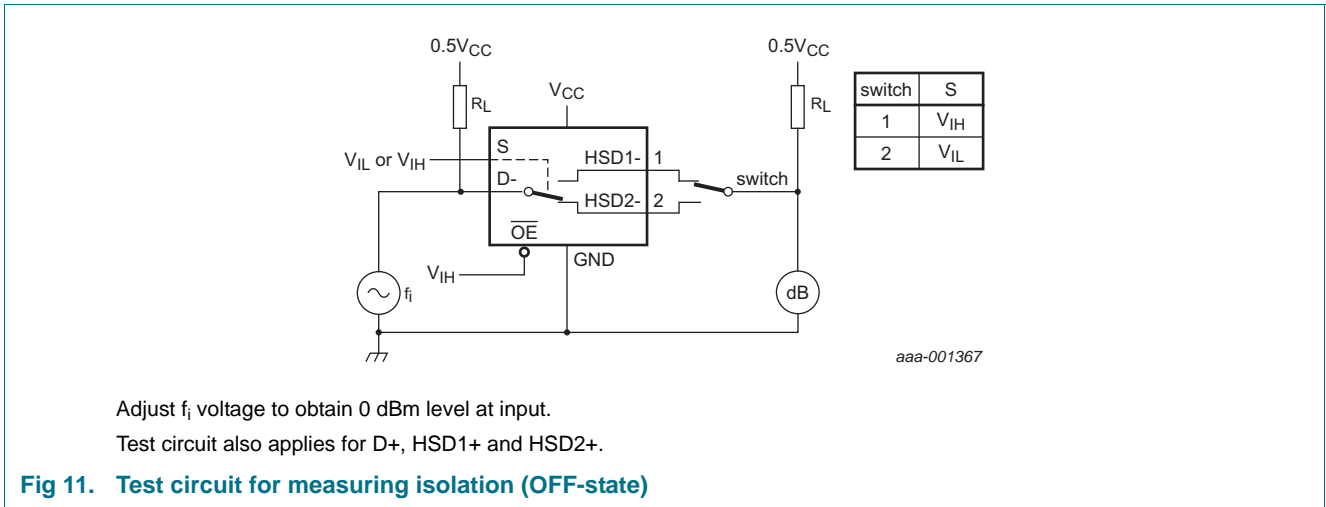
12.3 Test circuits

switch	S
1	$V_{IL}$
2	$V_{IH}$

aaa-001360

Adjust  $f_i$  voltage to obtain 0 dBm level at output. Increase  $f_i$  frequency until dB meter reads -3 dB.  
Test circuit also applies for D+, HSD1+ and HSD2+.

**Fig 10. Test circuit for measuring the frequency response when channel is in ON-state**



### 13. Package outline

XQFN10U: plastic extremely thin quad flat package; no leads; 10 terminals; UTLP based; body 2 x 1.55 x 0.5 mm

SOT1049-2

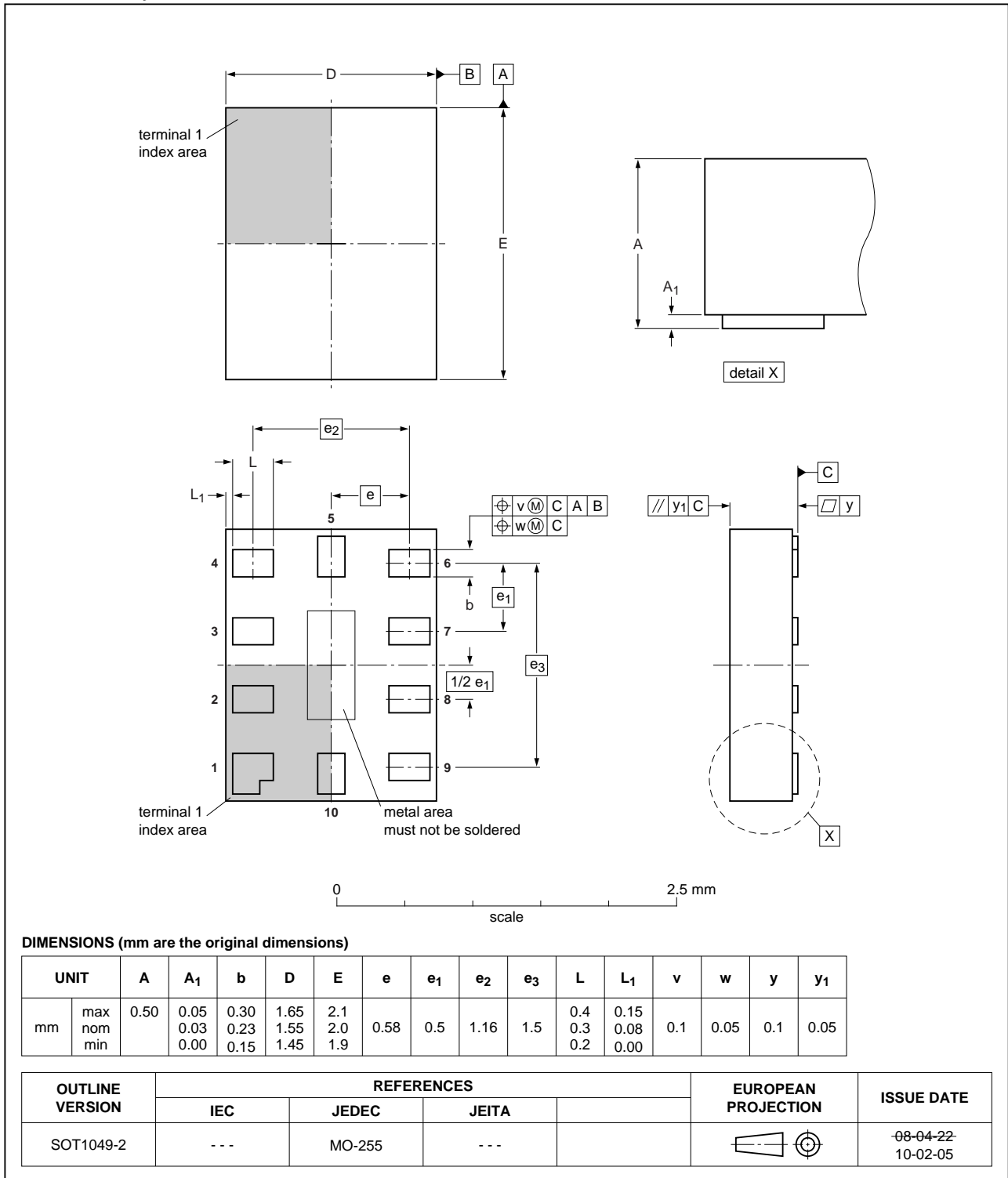


Fig 13. Package outline SOT1049-2 (XQFN10U)

XQFN10: plastic, extremely thin quad flat package; no leads; 10 terminals; body 1.40 x 1.80 x 0.50 mm

SOT1160-1

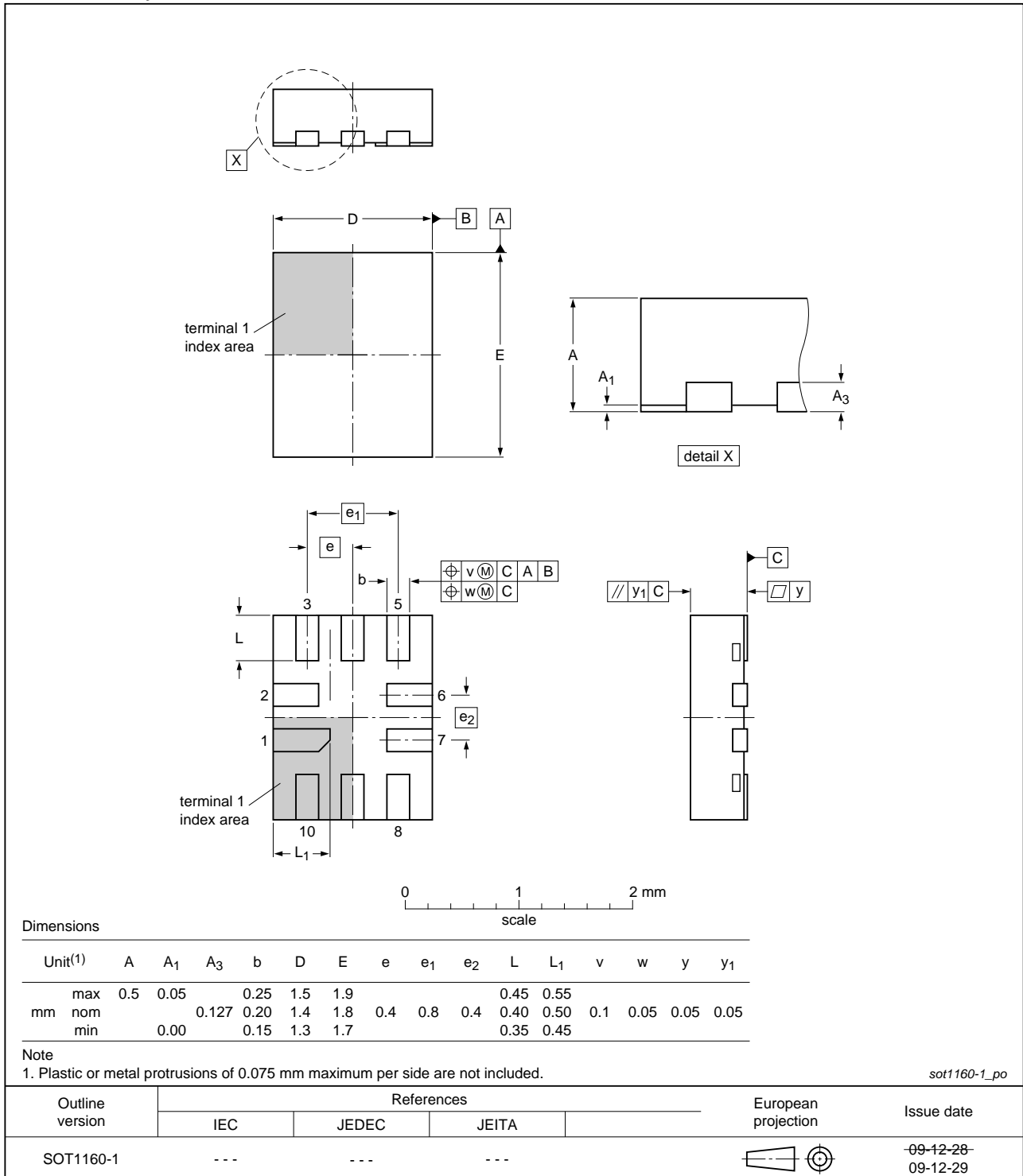


Fig 14. Package outline SOT1160-1 (XQFN10)

## 14. Abbreviations

Table 13. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

## 15. Revision history

Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
NX3DV42 v.1	20120103	Product data sheet	-	-

## 16. Legal information

### 16.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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